# MSKSEMI















**ESD** 

**TVS** 

**TSS** 

MOV

**GDT** 

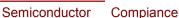
**PLED** 

Broduct data speet







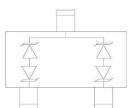


### **Features**

- 300 Watts peak pulse power (tp =  $8/20\mu$ s)
- Transient protection for high speed data lines to IEC 61000-4-2 (ESD) ±30kV (air), ±30kV (contact) IEC 61000-4-4 (EFT) 40A (5/50ns)
- Working voltages: 3V,5V,12V,15V,24V
- Protects two bidirectional line
- Low operating and clamping voltages
- Solid-state silicon avalanche technology

# **Applications**

- Notebooks, Desktops, Servers and Video Graphics Cards
- **USB Power & Data Line Protection**
- Monitors and Flat Panel Displays
- I<sup>2</sup>C Bus Protection
- Portable Instrumentation
- Set Top Box





**SOT-23** 

# Electrical Characteristics@ Ta=25<sup>°</sup>Cunless otherwise

PART	$V_{RWM}$	$V_{B}$	Ι <sub>Τ</sub>	Vc@1A	V	'c	I <sub>R</sub>	Ст
NUMBER	(V)	(V)	(mA)	(V)	(V)		(µA)	(pF)
NOWIDER	(max.)	(min.)		(max.)	(max.)	(@A)	(max.)	(max.)
ESD3V3L2BT-MS	3.3	4	1	7.0	14	18	1	100
ESD5V0L2BT-MS	5	6	1	9.8	18	13	1	75
ESD12VL2BT-MS	12	13.3	1	19	32	5	1	20
ESD15VL2BT-MS	15	16.7	1	24	38	5	1	20
ESD24VL2BT-MS	24	26.7	1	43	52	5	1	35

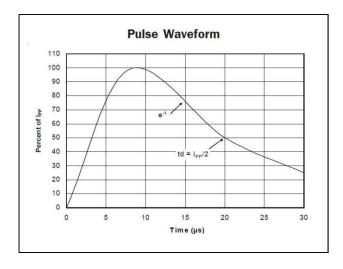
# Maximum Rating @ Ta=25 ° unless otherwisespecified

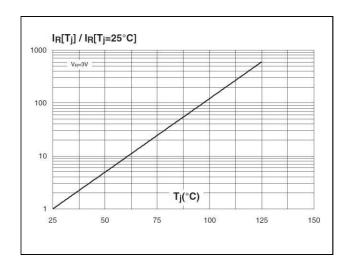
Symbol	Parameter	Ratings	Units
Ррк	Peak Pulse Power (tp = 8/20µs)	300	Watts
TL	Lead Soldering Temperature	260(10sec.)	${\mathbb C}$
TJ	Operating Temperature -55 to +125		${\mathbb C}$
T <sub>STG</sub>	Storage Temperature	-55 to +150	$^{\circ}$ C

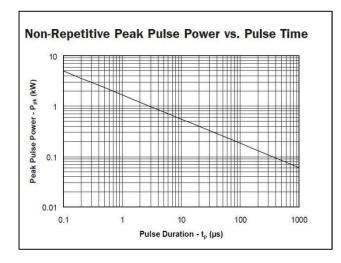


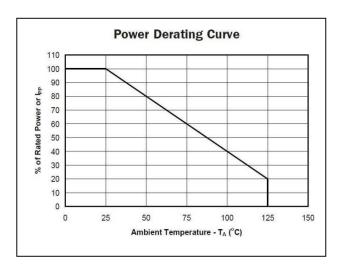


# Typical Characteristics@ Ta=25°C unless otherwise specified



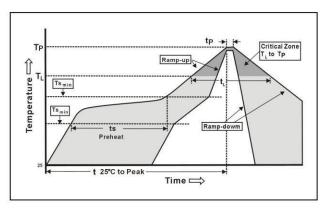






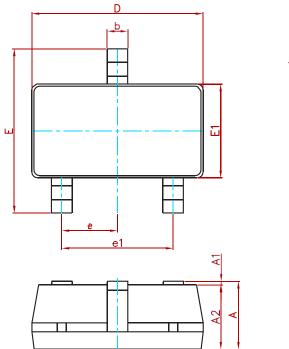
# **Soldering Parameters**

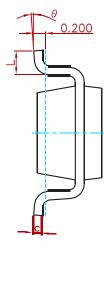
Reflow Condition		Fb – Free assembly	
	- Temperature Min (T <sub>s(Min)</sub> )	150°C	
Pre Heat	- Temperature Max (T <sub>s(Max)</sub> )	200°C	
	-Time (Min to max) (t <sub>s</sub> )	60 - 180 secs	
Average ramp up rate (Liquidus) Temp (T <sub>L</sub> ) to peak		3°C/second Max	
T <sub>s (Max)</sub> to T	- Ramp-up Rate	3°C/second Max	
Reflow	-Temperature (T <sub>L</sub> ) (Liquidus)	217°C	
	-Temperature (t <sub>L</sub> )	60 - 150 seconds	
Peak Temperature (T <sub>p</sub> )		250+0/-5 °C	
Time within 5°C of actual peak Temperature (t <sub>p</sub> )		20 – 40 seconds	
Ramp-dowm Rate		6°C/second Max	
Time 25°C to peak Temperature (T <sub>p</sub> )		8 minutes Max.	
Do not exceed		260°C	





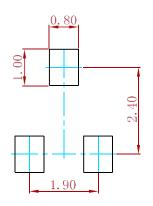
### **PACKAGE MECHANICAL DATA**





Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
Syllibol	Min.	Max.	Min.	Max.	
Α	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E1	1.500	1.700	0.059	0.067	
Е	2.650	2.950	0.104	0.116	
е	0.950(BSC)		0.037(BSC)		
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
0	0°	8°	0°	8°	

# **Suggested Pad Layout**



- 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
- 3. The pad layout is for reference purposes only.

# **REEL SPECIFICATION**

P/N	PKG	QTY
ESDXXVL2BT-MS	SOT-23	3000



Semiconductor

### Compiance

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